

Sense and Control



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High Precision Hall Effect Switches for Industrial and Consumer Applications

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Page	Subjects (major changes since last revision)							
-								

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High Precision Hall Effect Switch

TLI4906

1 Product Description

1.1 Overview

The TLI4906x is a high precision Hall Effect Switch with highly accurate switching thresholds for ambient operating temperatures up to 125°C.

The TLI4906K is available in a PG-SC59-3-4 package, the TLI4906L in a PG-SSO-3-2 package.

Infineon SC59

1.2 Features

- 2.7 V to 18 V supply voltage operation.
- · Operation from unregulated power supply.
- High sensitivity and high stability of the magnetic switching points.
- · High resistance to mechanical stress by active error compensation.
- Reverse battery protection (-18 V).
- · Superior temperature stability.
- Low jitter (typically 1 μs).
- High ESD performance (± 4 kV HBM).
- Digital output signal (open-drain).
- Not suitable for automotive applications



1.3 Target Applications

The TLI4906x is ideally suited for all industrial and consumer applications that require a high precision switching thresholds for position sensing. It can be used for example for: security systems, alignment control, push buttons, keyboards, key switches, machine tools, etc.

Product Name	Product Type	Ordering Code	Package
Hall Effect Switch	TLI4906K	SP000604306	PG-SC59-3-4
Hall Effect Switch	TLI4906L	SP000604320	PG-SSO-3-2

Datasheet 7 Rev. 1.0, 2009-05-04



Functional Description

2 Functional Description

2.1 General

Precise magnetic switching thresholds and high temperature stability are achieved by active compensation circuits and chopper techniques on chip. Offset voltages generated by temperature-induced stress or overmolding are canceled so that high accuracy is achieved. The IC has an open collector output stage with 20 mA current sink capability. A wide operating voltage range from 2.7 V to 18 V with reverse polarity protection down to -18 V makes the TLI4906xsuitable for a wide range of applications. A magnetic south pole with a field strength above B_{op} turns the output on. A magnetic north pole exceeding B_{rp} turns it off.

2.2 Pin Configuration

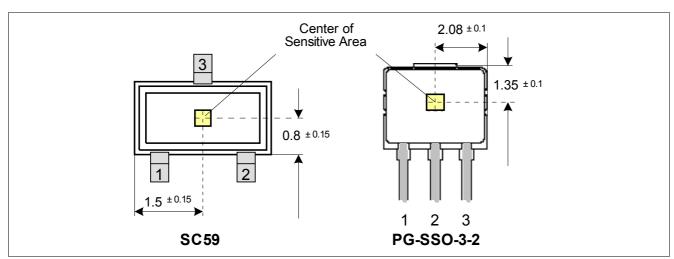


Figure 1 Pin Configuration and sensitive area (Top view, figure not to scale)



Functional Description

2.3 Pin Description

Table 1 PIN Definitions for the PG-SC59-3-4 package

PIN No.	Name	Function
1	V_s	Supply Voltage
2	Q	Output
3	GND	Ground

Table 2 PIN Definitions for the PG-SSO-3-2 package

PIN No.	Name	Function
1	V _s	Supply Voltage
2	GND	Ground
3	Q	Output

2.4 Block Diagram

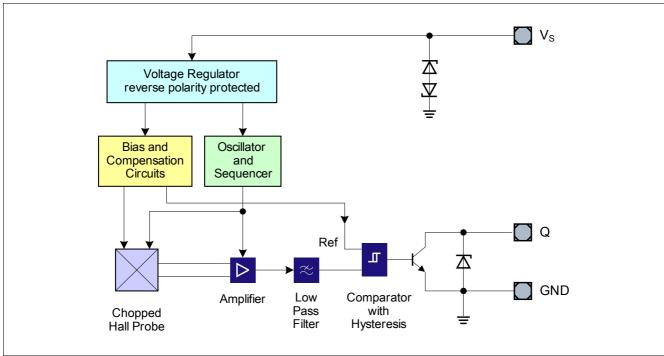


Figure 2 TLI4906x Block Diagram



Functional Description

2.5 Operating Modes and States

Field Direction and Definition

Positive magnetic fields correspond to the south pole of the magnet targeting the branded side of the package.

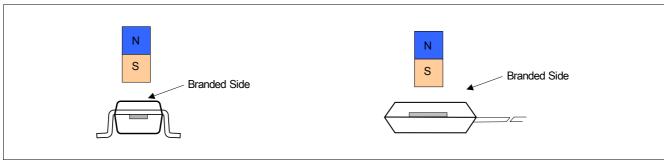


Figure 3 Definition of the Magnetic Field direction

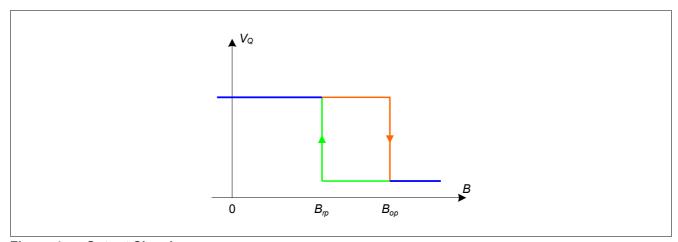


Figure 4 Output Signal

2.6 Functional Block Description

The chopped Hall Effect Switch comprises a Hall probe, a bias generator, compensation circuits, an oscillator and an output transistor. The bias generator provides currents to the Hall probe and the active circuits. Compensation circuits stabilize response of the IC over temperature and reduce the impact of process variations.

The Active Error Compensation rejects offsets in the signal path and reduces the impact of mechanical stress in the package caused by molding, soldering and thermal effects.

The chopper technique together with the threshold generator and the comparator ensure high accurate magnetic switching points.



Specification

3 Specification

3.1 Application circuit

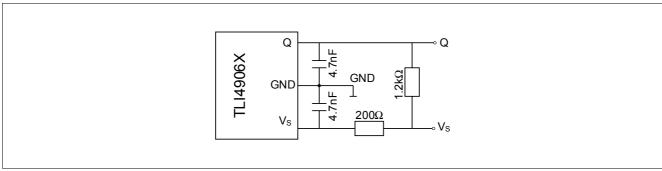


Figure 5 Application circuit

It is recommended to use a resistor of 200 Ω in the supply line for current limitation in the case of an overvoltage pulse. Two capacitors of 4.7 nF enhance the EMC performance. The pull-up of 1.2 k Ω limits the current through the output transistor.

3.2 Absolute Maximum Ratings

Stress above the maximum values listed in this section may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect the reliability of the device. Exceeding only one of these values may cause irreversible damage to the device.

Table 3 Absolute Maximum Ratings

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Maximum Ambient Temperature	T_{A}	- 40	_	125	°C	
Maximum Junction Temperature	T_{J}	- 40	_	150	°C	
Supply Voltage	V_{S}	- 18	_	18	V	
Supply current through protection device	$I_{\mathbb{S}}$	-50	_	50	mA	
Output Voltage	V_{OUT}	- 0.7	_	18	V	
Storage Temperature	T_{S}	- 40	_	150	°C	
Magnetic flux density	В	_	_	unlimited	mT	
ESD Robustness HBM: 1.5 kΩ, 100 pF	$V_{\rm ESD,HBM}^{-1)}$	_	_	4	kV	

¹⁾ According to EIA/JESD22-A114-E



Specification

3.3 Operating Range

The following operating conditions must not be exceeded in order to ensure correct operation of the TLI4906x. All parameters specified in the following sections refer to these operating conditions unless otherwise mentioned.

Table 4 Operating Range

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Supply Voltage	V_{S}	2.7	_	18	V	
Output Voltage	V_{Q}	-0.7	_	18	V	
Output Current	I_{Q}	0	_	20	mA	
Maximum Ambient Temperature	T_{A}	-40	_	125	°C	

3.4 Electrical Characteristics

Product characteristics include the spread of values guaranteed within the specified voltage and ambient temperature range. typical characteristics are the median of the production (at V_s =12V and T_A =25°C).

Table 5 Electrical Characteristics

Parameter	Symbol	Values			Unit	Note / Test Condition	
		Min.	Тур.	Max.			
Supply Current	I_{S}	2	4	6	mA	V _S =2.7 V18 V	
Reverse Current	I_{SR}	0	0.2	1	mA	V _S =-18 V	
Output Saturation Voltage	V_{QSAT}	_	0.3	0.6	V	I _Q =20 mA	
Output leakage current	I_{QLEAK}	_	0.05	10	μΑ	V _Q =18 V	
Output fall time ¹⁾	t_{f}	_	0.02	1	μs	R_L =1.2k Ω , C_L =50 pF	
Output rise time ¹⁾	t_{r}	_	0.4	1	μs		
Chopper frequency	$f_{ m OSC}$	_	320	_	kHz		
Switching frequency	$f_{\sf SW}$	0	_	15 ²⁾	kHz		
Delay time ³⁾	$t_{\sf d}$	_	13	_	μs		
Output jitter ⁴⁾	t_{QJ}	-	1	-	μs _{RMS}	Typical value for a 1 kHz square wave signal	
Power-on Time ⁵⁾	t_{PON}	_	13	_	μs	V _S > 2.7 V	
Thermal Resistance junction to	R_{thja}	_	100	_	K/W	TLI4906K	
ambient ⁶⁾		_		190	K/W	TLI4906L	

¹⁾ See Figure 6

²⁾ To operate the sensor at maximum switching frequency, the value of the magnetic signal amplitude must be 1.4 times higher than the static fields. This is due to the -3 dB corner frequency of the low pass filter in the signal path.

³⁾ Systematic delay between magnetic threshold reached and output.

⁴⁾ Jitter is the unpredictable deviation of the output switching delay.

⁵⁾ Time from applying V_{S} > 2.7 V to the sensor until the output state is valid.

⁶⁾Relationship between junction and ambient temperature: $T_J = T_{amb} + R_{thja}$. $(V_S . I_S + V_{QS} . I_Q)$.



Specification

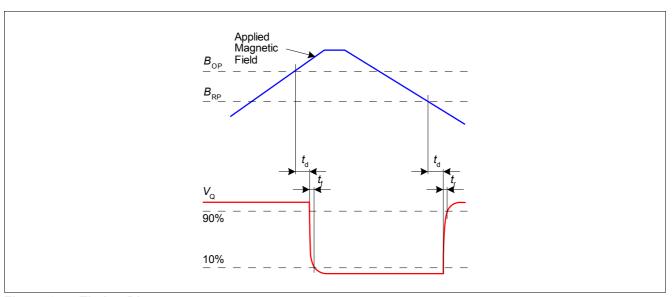


Figure 6 Timing Diagram

Table 6 Magnetic Characteristics 1)

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Тур.	Max.		
Operate point	B_{OP}	6.2	10.0	13.9	mT	
Release point	B_{RP}	4.7	8.5	12.3	mT	
Hysteresis	B_{HYS}	0.7	1.5	3.0	mT	2)
Temperature compensation of magnetic thresholds	TC	_	-350	_	ppm/°C	
Repeatability of magnetic thresholds ³⁾	B_{REP}	-	20	_	μT_{RMS}	typical value for ΔB/Δt > 12mT/ms

¹⁾ Over all operating conditions.

²⁾ At 25°C.

³⁾ B_{REP} is equivalent to the noise constant.

Package Information

4 Package Information

4.1 TLI4906K Package Outline

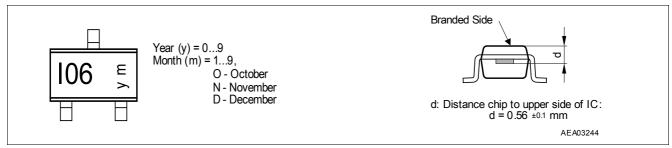


Figure 7 Marking of the TLI4906K and distance of the chip to the upper side

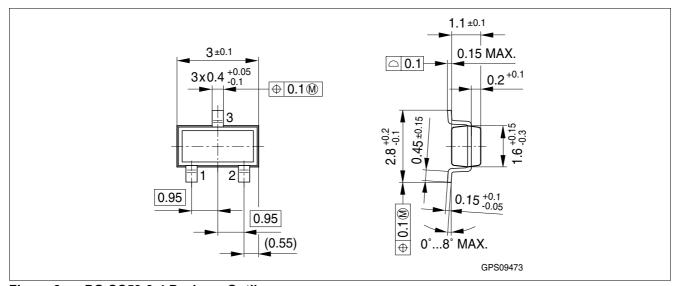


Figure 8 PG-SC59-3-4 Package Outline



Package Information

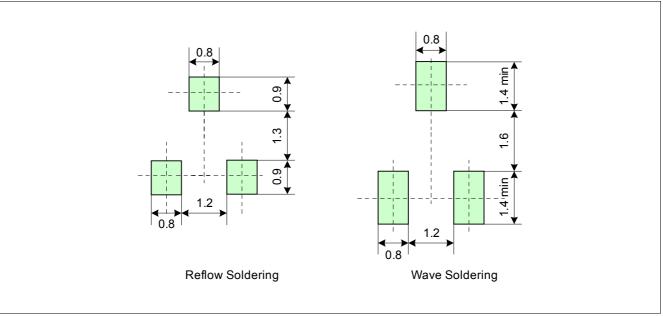


Figure 9 Footprint PG-SC59-3-4 (SOT23 compatible)

4.2 TLI4906L Package Outline

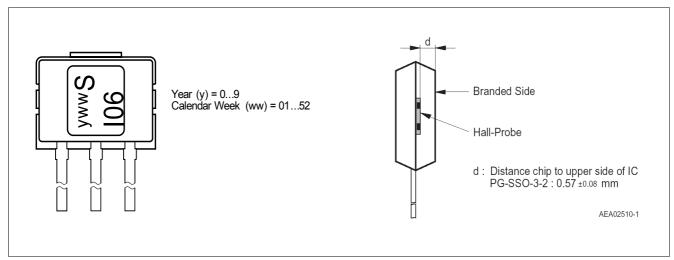


Figure 10 Marking of the TLI4906L and distance of the chip to the upper side



Package Information

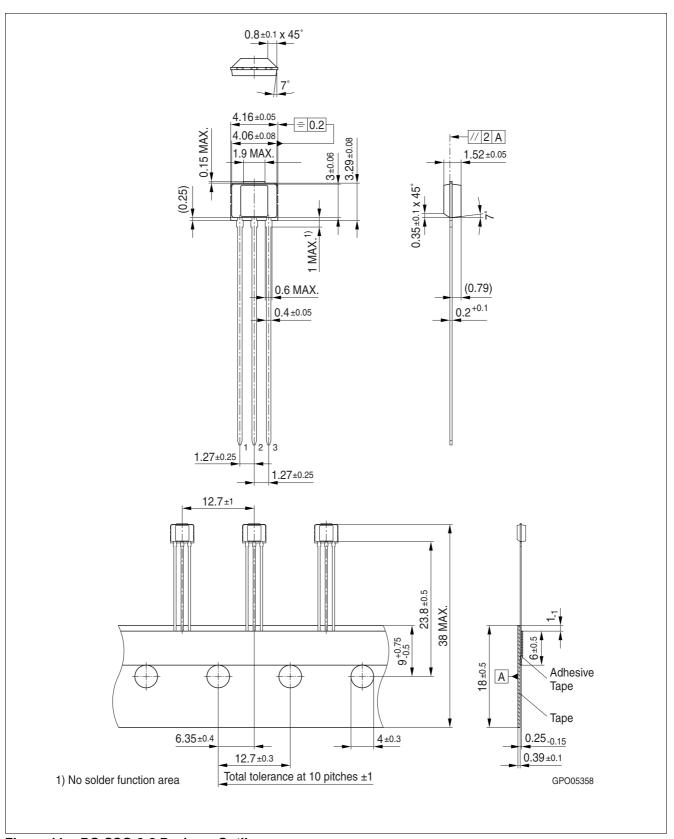


Figure 11 PG-SSO-3-2 Package Outline

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